3-Axis Programmable Hall Effect Latch/Switch Datasheet



#### **1. Features and Benefits**

- Triaxis® Hall Technology
- Dual Hall outputs
  - Two independent X, Y or Z magnetically sensitive open drain outputs
  - Quadrature outputs (90° phase shift) for pitch-independent design
  - Programmable independent magnetic thresholds and temperature coefficient
- High ESD capability and EMC robustness for PCB-less applications
- Programmable magnetic Latch, Unipolar or Omnipolar Switch functions
- Speed, Direction or Pulse output functions
- Selectable power-on state using start-up feedback to avoid miscounting
- Wide magnetic range from 0.5mT to 40mT
- Wide operating voltage range 2.7V to 60V
- 48V board net compatibility
- Low current consumption of 1.9mA
- Packages, RoHS compliant
  - VA-4L (PCB-less)
  - TSOT23-5L (SMD)
- AEC-Q100 and ASIL A capable device
- Integrated protections
  - Reverse supply voltage protection
  - Output short circuit protection by Thermal protection
  - Under-voltage reset

#### 2. Application Examples

- Linear speed & direction control: power liftgate, closures with anti-pinch
- Incremental rotary encoding: cadence sensor for e-bikes, DC motor indexing, fan & pump motors
- Dual linear position detection: piston, lever, stalks, valves
- Angular position detection: knobs, jog wheels

#### **3. Description**

The MLX92352/1 is a monolithic sensor IC sensitive to magnetic field applied to X, Y and Z axes of the package. Any axes combination ZX, ZY, XY, XX, YY or ZZ on its open drain outputs is possible. It provides the customer ultimate configurability with its 90 degrees phase shift for a pitch independent magnetic design.

The device enables PCB-less module designs to save on your total cost of ownership without the need of external passive components. The MLX92352/1 withstands 15kV HBM, 8kV System ESD and it has high EMC robustness.

The MLX92352/1 can be programmed to act as magnetic latch, unipolar switch or omnipolar switch. The magnetic thresholds  $B_{OP}$  and  $B_{RP}$  can be programmed independently for each axis. Furthermore, the MLX92352/1 processes digitally the magnetic signal and outputs Speed, Direction or Pulse on its outputs.

The MLX92352/1 can be used to detect the rotation speed and direction of a ring magnet when configured as a dual magnetic latch. It can also switch on two independent magnet positions for complex position designs.

Customers can benefit from the end-of-line (EoL) programming capability of the MLX92352 to trim mechanical tolerances away or alternatively choose a pre-programmed MLX92351 device. Programming is available with the PTC04 or EVB2.



MLX92352/1 functional diagram

3-Axis Programmable Hall Effect Latch/Switch Datasheet



## Contents

1. FEATURES AND BENEFITS	1
2. APPLICATION EXAMPLES.	1
3. DESCRIPTION.	1
4. ORDERING INFORMATION	
5. PIN DEFINITIONS AND DESCRIPTIONS.	
5.1. Pin Definition for SE package	
5.2. Pin Definition for VA package	
6. GLOSSARY OF TERMS	
7. ABSOLUTE MAXIMUM RATINGS	
8. GENERAL ELECTRICAL SPECIFICATIONS.	
9. VERSION SPECIFIC PARAMETERS.	
9.1. MLX92352LVA-BAB-000-BU/ MLX92352LSE-BAA-000-BU	
10. DETAILED DESCRIPTION	
10.1. Start-Up feedback 10.2. Thermal protection function	
10.3. Brownout reset function	
10.4. Output functions	
10.4.1. Speed/Speed 10.4.2. Speed/Direction	
10.4.2. Speed/Direction	
11. MAGNETIC BEHAVIOR.	
11.1. Active magnetic pole definition	
11.2. Latch Sensor	
11.2. Lateri Sensor	
11.3. Ompolar Switch Sensor	
11.4. On hip of a Switch Sensor	
11.5.1. TSOT-5L package	
11.5.2. VA package	
12. TYPICAL APPLICATION SCHEMATIC	
13. PACKAGE INFORMATION	
13.1. TSOT-5L (SE Package)	
13.1.1. TSOT-5L – Package dimensions	
13.1.2. TSOT-5L – Sensitive spot	
13.1.3. TSOT-5L – Package marking	
13.2. VA package	
13.2.1. VA – Package dimensions	
13.2.2. VA – Sensitive spot	
13.2.3. VA – Package marking	
14. STANDARD INFORMATION	
14.1. Storage and handling of plastic encapsulated ICs	
14.2. Assembly of encapsulated ICs	
14.3. Environment and sustainability	
15. ESD PRECAUTIONS	24
16. CONTACT	25
17. DISCLAIMER	25

3-Axis Programmable Hall Effect Latch/Switch Datasheet



# 4. Ordering Information

Product	Temperature	Package	Option Code	Packing Form	Definition
MLX92352	L	VA	BAB-000	BU	Customer EoL programmable 4-wire sensor
MLX92352	L	SE	BAA-000	RE	Customer EoL programmable 4-wire sensor

# Legend:

Product	MLX9235 <u>1</u> – Factory Pre-Programmed 4-wire sensor MLX9235 <u>2</u> – Customer EoL Programmable 4-wire sensor			
Temperature Code:	L: T <sub>A</sub> from -40°C to 150°C			
Package Code:	"VA" for VA package "SE" for TSOT-5L			
Option Code:	<ul> <li>BA<u>A</u> = X/Y/Z-axis sensitive sensor</li> <li>BA<u>B</u> = Z/X-axis sensitive sensor</li> <li>BA<u>C</u> = Z/Y-axis sensitive sensor</li> <li>BA<u>D</u> = X/Y-axis sensitive sensor</li> <li>BA<u>E</u> = Z-axis sensitive sensor</li> <li>BA<u>F</u> = X-axis sensitive sensor</li> <li>BA<u>G</u> = Y-axis sensitive sensor</li> </ul>			
Packing Form:	BU: Bulk RE: Reel			
Ordering Example:	MLX92352LVA-BAB-000-BU			

3-Axis Programmable Hall Effect Latch/Switch Datasheet



# 5. Pin Definitions and Descriptions

# 5.1. Pin Definition for SE package



Pin #	Name	Description	
1	OUT2	Open-Drain Output 2	
2	OUT1	Open-Drain Output 1	
3	VDD	Power Supply	
4	GND	Ground pin	
5	GND	Ground pin	

Note: Both GND pins should be connected (pin 4 and pin 5)

#### 5.2. Pin Definition for VA package



Pin #	Name	Description	
1	OUT1	Open-Drain Output 1	
2	VDD	Power Supply	
3	GND	Ground pin	
4	OUT2	Open-Drain Output 2	

3-Axis Programmable Hall Effect Latch/Switch Datasheet



## 6. Glossary of Terms

Term	Definition			
Gauss (G), Tesla (T)	Units for the magnetic flux density $-1 \text{ mT} = 10 \text{ G}$			
ТС	Temperature Coefficient of the magnetic threshold (in ppm/°C)			
ADC	Analog-to-Digital Converter			
B <sub>OP</sub>	Operating magnetic threshold			
B <sub>RP</sub>	Release magnetic threshold			

# 7. Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Supply voltage <sup>(1)</sup>	V <sub>DD</sub>	70	V
Reverse supply voltage <sup>(1)</sup>	V <sub>DDREV</sub>	-40	V
Output voltage <sup>(1)</sup>	V <sub>OUT</sub>	70	V
Reverse output voltage	VOUTREV	-0.5	V
Output current	I <sub>OUT</sub>	30	mA
Reverse output current	I <sub>OUTREV</sub>	-50	mA
Maximum junction temperature <sup>(2)</sup>	TJ	+175	°C
ESD – HBM <sup>(3)</sup>	-	15	kV
$ESD - CDM^{(4)}$	-	1	kV
ESD – System <sup>(5)</sup>	-	8	kV

Exceeding the absolute maximum ratings may cause permanent damage. Exposure to absolute maximum-rated conditions for extended periods may affect device reliability.

<sup>&</sup>lt;sup>1</sup> For maximum 1 hour

<sup>&</sup>lt;sup>2</sup> Guaranteed by 1000 hours HTOL

<sup>&</sup>lt;sup>3</sup> Human Body Model according AEC-Q100-002 standard

<sup>&</sup>lt;sup>4</sup> Charged Device Model according AEC-Q100-011 standard

<sup>&</sup>lt;sup>5</sup> Unpowered Contact discharge (150pF/330Ω), GND connected to the horizontal coupling plane, ISO10605

3-Axis Programmable Hall Effect Latch/Switch Datasheet



# 8. General Electrical Specifications

#### Operating conditions $V_{DD} = 2.7V$ to 60V, $T_A = -40^{\circ}$ C to 150°C (unless otherwise specified)

Electrical Parameter	Symbol	Condition	Min	Typ <sup>(1)</sup>	Max	Unit
Brownout reset threshold	V <sub>BOR</sub>		-	_	2.6	V
Brownout duration	t <sub>BO</sub>	2	-	-	1.4	S
Under Voltage Reset threshold	V <sub>UVR</sub>		_	-	2.1	V
Under Voltage Reset reaction time <sup>(3)</sup>	t <sub>UVR</sub>	$V_{DD}$ drop to 1.5V	-	1	-	μs
Output leakage		V <sub>OUT</sub> = 12V <sup>(3)</sup>	-	-	1	μΑ
Output leakage	I <sub>OFF</sub>	V <sub>OUT</sub> = 60V	-	-	10	μΑ
Output saturation voltage	V <sub>OL</sub>	$I_{OL} = 10 \text{mA}^{(2)}$	-	0.15	0.4	V
Output saturation voltage	VOL	I <sub>OL</sub> = 20mA	-	0.3	0.8	V
Output resistance	R <sub>OL</sub>	I <sub>OL</sub> = 20mA	-	15	40	Ω
Output rise time <sup>(3,4)</sup>	t <sub>R</sub>	$R_{PU} = 4.7 k\Omega, V_{DD} = 12V,$ $V_{PU} = 5V, C_{LOAD} = 50 pF$	0.3	0.5	1	μs
Output fall time <sup>(3,4)</sup>	t <sub>F</sub>	$R_{PU} = 4.7 k\Omega, V_{DD} = 12V,$ $V_{PU} = 5V, C_{LOAD} = 50 pF$	0.2	0.4	1	μs
		$V_{DD} = 5V, \Delta V_{DD}/\Delta t \ge 2V/\mu s$ dual axis configuration	-	75	110	μs
		$V_{DD} = 5V, \Delta V_{DD}/\Delta t \ge 2V/\mu s$ single axis configuration	-	60	95	μs
Power-On time <sup>(5,6,7)</sup>	t <sub>on</sub>	$V_{DD} = 5V, \Delta V_{DD}/\Delta t \ge 2V/\mu s$ dual axis configuration with Fast Start-Up enabled	_	60	95	μs
		$V_{DD} = 5V, \Delta V_{DD}/\Delta t \ge 2V/\mu s$ single axis configuration with Fast Start-Up enabled	_	50	75	μs

<sup>1</sup> Unless otherwise specified the typical values are defined at  $T_A = +25$ °C and  $V_{DD} = 12V$ 

<sup>&</sup>lt;sup>2</sup> Guaranteed by correlation with production test at  $T_A$ =150°C and verified by characterization

<sup>&</sup>lt;sup>3</sup> Guaranteed by design and verified by characterization, not production tested

<sup>&</sup>lt;sup>4</sup>  $R_{PU}$  and  $V_{PU}$  are respectively the external pull-up resistor and pull-up power supply

<sup>&</sup>lt;sup>5</sup> The Power-On Time represents the time from reaching  $V_{DD}$  = 2.7V to the first refresh of OUT1 and OUT2 state

<sup>&</sup>lt;sup>6</sup> Power-On Slew Rate is not critical for proper device start-up.

<sup>&</sup>lt;sup>7</sup> Using Fast Start-up option may add up to ±2mT of additional offset for the first magnetic conversion.

3-Axis Programmable Hall Effect Latch/Switch Datasheet



Electrical Parameter	Symbol	Condition	Min	Typ <sup>(1)</sup>	Max	Unit
Power-On state	-	Output state during toN		High		-
Maximum switching		Triangular magnetic field with B <sub>PEAK</sub> ≥10xB <sub>OP</sub> ; single axis, magnetic latch	37	42	-	kHz
frequency <sup>(2)</sup>	F <sub>SW_MAX</sub>	Triangular magnetic field with B <sub>PEAK</sub> ≥10xB <sub>OP</sub> ; dual axis, magnetic latch	21	24	-	kHz
		Triangular magnetic field with B <sub>PEAK</sub> ≥10xB <sub>OP</sub> , F <sub>B</sub> =10kHz; single axis, magnetic latch	_	18	_	μs
Propagation delay <sup>(2)</sup>	t <sub>PD</sub>	Triangular magnetic field with B <sub>PEAK</sub> ≥10xB <sub>OP</sub> , F <sub>B</sub> =10kHz; dual axis, magnetic latch	_	25	_	μs
$O_{1}$		Triangular magnetic field with $B_{PEAK} \ge 10 \times B_{OP}$ , $F_B = 10 \times Hz$ ; single axis, magnetic latch	_	9	_	μs
Output jitter (p-p) <sup>(2)</sup>	t <sub>JITTER</sub>	Triangular magnetic field with $B_{PEAK} \ge 10 \times B_{OP}$ , $F_B = 10 \times Hz$ ; dual axis, magnetic latch	-	22	-	μs
Start-up feedback High-level input voltage	V <sub>SFB_IH</sub>		1.4	_	-	V
Start-up feedback Low-level input voltage	V <sub>SFB_IL</sub>		_	_	0.8	v
Supply current	I <sub>DD</sub>		-	1.9	2.4	mA
Supply current in Thermal Protection	I <sub>DD_TPROT</sub>		_	0.43	0.75	mA
Reverse supply current	I <sub>DDREV</sub>	V <sub>DD</sub> = -30V	-1	_	_	mA
Thermal Protection threshold	T <sub>PROT</sub>		_	200	_	°C
VA package thermal resistance	R <sub>thja</sub>	Single layer PCB, JEDEC standard test boards, still air (LFPM=0)	_	170	-	°C/W
SE package thermal resistance	R <sub>thja</sub>	Single layer PCB, JEDEC standard test boards, still air (LFPM=0)	_	300	_	°C/W

<sup>&</sup>lt;sup>1</sup> Unless otherwise specified the typical values are defined at  $T_A = +25$  °C and  $V_{DD} = 12V$ <sup>2</sup> Guaranteed by design and verified by characterization, not production tested

3-Axis Programmable Hall Effect Latch/Switch Datasheet



### 9. Version Specific Parameters

#### 9.1. MLX92352LVA-BAB-000-BU/ MLX92352LSE-BAA-000-BU

Operating conditions  $V_{DD} = 2.7V$  to 60V,  $T_A = -40^{\circ}$ C to 150°C (unless otherwise specified)

Magnetic Parameter	Symbol	Condition	Min	Typ <sup>(1)</sup>	Max	Unit
		T <sub>A</sub> = -40°C	0.7	2	3.3	
Operating point Output 1	B <sub>OP_OUT1</sub>	T <sub>A</sub> = 25°C	1.1	2	2.9	mT
		T <sub>A</sub> = 150°C	0.7	2	3.3	
		T <sub>A</sub> = -40°C	-3.3	-2	-0.7	
Release point Output 1	B <sub>RP_OUT1</sub>	T <sub>A</sub> = 25°C	-2.9	-2	-1.1	mT
		T <sub>A</sub> = 150°C	-3.3	-2	-0.7	
	B <sub>OP_OUT2</sub>	T <sub>A</sub> = -40°C	-3.3	-2	-0.7	mT
Operating point Output 2		T <sub>A</sub> = 25°C	-2.9	-2	-1.1	
		T <sub>A</sub> = 150°C	-3.3	-2	-0.7	
		T <sub>A</sub> = -40°C	0.7	2	3.3	
Release point Output 2	B <sub>RP_OUT2</sub>	T <sub>A</sub> = 25°C	1.1	2	2.9	mT
		T <sub>A</sub> = 150°C	0.7	2	3.3	
Temperature coefficient <sup>(2)</sup>	тс			0		ppm/°C

	Sensitive axis	Magnetic function	Active pole	Output polarity	Output function	Direction pin polarity <sup>(3)</sup>	Start-up feedback	Fast Start-up
Output 1	х	Latch	South	-	Speed		No	No
Output 2	Z	Latch	North	-	Speed	-	NO	No

$$TC = \frac{B_{XPTA2} - B_{XPTA1}}{B_{XPTA1} \times (T_{A2} - T_{A1})} \times 10^{6}, ppm/^{\circ}C$$

where:

 $T_{A1} = 25^{\circ}C, T_{A2} = 150^{\circ}C$ 

<sup>&</sup>lt;sup>1</sup> Unless otherwise specified the typical values are defined at  $T_A = +25$  °C and  $V_{DD} = 12V$ 

<sup>&</sup>lt;sup>2</sup> The Temperature Coefficient is calculated using following formula:

In case of magnetic Latch application:  $B_{XPTA1}$  ( $B_{XPTA2}$ ) =  $B_{OP}$ - $B_{RP}$  at  $T_{A1}$  ( $T_{A2}$ )

In case of magnetic Switch application:  $B_{XPTA1}$  ( $B_{XPTA2}$ ) =  $B_{OP}$  or  $B_{RP}$  at  $T_{A1}$  ( $T_{A2}$ )

<sup>&</sup>lt;sup>3</sup> The Direction pin polarity is valid for the indexing magnet reference positions in chapter 11.5

3-Axis Programmable Hall Effect Latch/Switch Datasheet



### **10. Detailed Description**

#### 10.1. Start-Up feedback

The start-up feedback function essentially turns the two outputs into inputs during the Power-On time. After the elapse of  $t_{ON}$  the chip will use the externally provided state to set the references of the magnetic comparators to  $B_{OP}$  or  $B_{RP}$  for the corresponding magnetic axis. After  $t_{ON}$  the output state will correspond to the applied magnetic field. If the applied magnetic field is not leading to a change of the output state the state will remain the same as the one externally provided during power-on.

The Start-Up feedback function is particularly usefully in applications where the power supply of the chip is controlled by an MCU. This function is enabling the possibility to recover the state of the chip to the last known state prior the power-down of the chip. The Start-Up feedback function can be enabled/disabled by the customers during end-of-line programming for MLX92352 or pre-programed for MLX92351.

A typical application schematic is shown below.



IO1 pin of the MCU should be a push-pull type. IO2 and IO3 pins should be open drain type in order to avoid an excessive current trough the MCU's IO pins and MLX92352/1 outputs in case of output state conflict during  $t_{ON}$ . If open drain type of IO pins is not available, push-pull IO pins can be used with the following procedure. High state can be achieved by setting the IO pin to an input. For low state, the IO pin should be configured to an output with logic state low.

3-Axis Programmable Hall Effect Latch/Switch Datasheet





In the timing diagram above  $t_{sw}$  is the time from applying power to MLX92352/1 to providing a valid state on OUT1 and OUT2 from the MCU. This time should not exceed 10µs, it can be zero or negative, there is no limit in this direction. Therefore, it is permitted to provide a valid Start-Up state to the chip before providing the supply voltage.

After  $t_{ON}$ , IO2 and IO3 pins should be switched to input and the state of the pins can be read. The state is controlled by MLX92352/1 after  $t_{ON}$ .

#### 10.2. Thermal protection function

The Thermal Protection function is constantly monitoring the junction temperature  $(T_1)$  of the device. If T<sub>J</sub> is higher than the Thermal Protection threshold (T<sub>PROT</sub>) the current consumption of the device is reduced to I<sub>DD\_TPROT</sub>, both outputs are switched off and the magnetic measurements are disabled. Once T<sub>1</sub> drops and stays below the T<sub>PROT</sub> threshold for 200ms, the device resumes normal operation. The Thermal Protection function is used for overload protection of the outputs (e.g. short circuit to VDD).



#### 10.3. Brownout reset function

MLX92352/1 can tolerate a supply voltage drop below  $V_{BOR}$ , but above  $V_{UVR}$ , for a limited amount of time  $t_{BO}$  without resetting. If  $t_{BO}$  is exceeded, the device will enter reset state. In order for the device to exit the reset state the  $V_{DD}$  should be higher than  $V_{BOR}$ . If the supply voltage drops below  $V_{UVR}$  for more than  $t_{UVR}$  the MLX92352/1 is reset.

3-Axis Programmable Hall Effect Latch/Switch Datasheet



#### 10.4. Output functions

The MLX92352/1 can provide to its outputs unprocessed result from the comparison of the applied magnetic field and the pre-programmed magnetic thresholds. This type of output function is called Speed/Speed.

The chip can also provide to its outputs processed versions of the magnetic signal called Speed/Direction and Pulse/Direction. These functions are using the result from the magnetic comparison and further processing it to extract the information for the rotation direction.

Speed/Speed, Speed/Direction and Pulse/Direction output functions are typically used with magnetic Latch configuration.

The output functions can be configured by the user for MLX92352 or by Melexis for MLX92351 versions.

#### 10.4.1. Speed/Speed

The effect of the Speed/Speed function over the output behavior is demonstrated on the diagram below. It is shown how the state of the outputs is changing in relation to the position of the magnet for this particular configuration (Z/X, South Pole active Latch). In Speed/Speed mode the MLX92352/1 effectively outputs a quadrature signal. The direction of the rotation/movement, the position (number of poles passed by) and the speed of the rotation/movement of the magnet can be extracted using further analysis of the signal from the two outputs.



The MLX92352/1 provides the flexibility to assign the two outputs to any magnetic axis with arbitrary magnetic thresholds for each axis, including arbitrary combination of South Pole and North Pole active Latch.

#### MLX92352/MLX92351 3-Axis Programmable Hall Effect Latch/Switch Datasheet



#### 10.4.2. Speed/Direction

The Speed/Direction functionality is shown on the diagram below. The chip is using one of the magnetic axis to output the Speed signal. The Speed signal is typically used to count the number of pole-pairs passed by the chip and the rotational/linear speed of the magnet. The Direction signal is generated using both magnetic axis in order to evaluate the direction of the movement of the magnet.



The Speed and Direction signals can be inverted independently. Similar to Speed/Speed an arbitrary combination of magnetic axis can be configured for Speed/Direction function. Speed and Direction signals can be assigned to any of the two outputs. The Direction signal is always updated before the Speed signal. The delay of the Speed signal with respect to the Direction signal ( $t_{DS}$ ) is typically 4 $\mu$ s.

#### 10.4.3. Pulse/Direction

The Pulse/Direction functionality is demonstrated on the diagram below. The major difference between Pulse/Direction and Speed/Direction is the usage of both magnetic axes to generate the Pulse signal. In this way, two times the angular/linear resolution is achieved with the same magnet versus the Speed/Direction function. The Pulse signal is typically used to count the number of poles passed by the chip and the rotational/linear speed of the magnet. The Direction signal is generated using both magnetic axis in order to evaluate the direction of the movement of the magnet.

3-Axis Programmable Hall Effect Latch/Switch Datasheet





The Pulse and Direction signals can be inverted independently. Similar to Speed/Speed an arbitrary combination of magnetic axis can be configured for Pulse/Direction function. Pulse and Direction signals can be assigned to any of the two outputs. The Direction signal is always updated before the Pulse signal. The delay of the Pulse signal with respect to the Direction signal ( $t_{DS}$ ) is typically 4 $\mu$ s.

3-Axis Programmable Hall Effect Latch/Switch Datasheet



## **11. Magnetic Behavior**

The MLX92352/1 can be programmed to act as magnetic Latch, Unipolar Switch or Omnipolar Switch. The magnetic function, thresholds and active magnetic axis can be programmed individually for each output. The magnetic behavior can be configured by the user for MLX92352 or by Melexis for MLX92351 versions.

#### 11.1. Active magnetic pole definition



SE package North Pole Active for X,Y and Z axis



VA package North Pole Active for X,Y and Z axis



SE package South Pole Active for X,Y and Z axis



VA package South Pole Active for X,Y and Z axis

3-Axis Programmable Hall Effect Latch/Switch Datasheet



#### 11.2. Latch Sensor



Direct South Pole Active Switch

Inverted South Pole Active Switch



3-Axis Programmable Hall Effect Latch/Switch Datasheet



Direct North Pole Active Switch

Inverted North Pole Active Switch

# 11.4. Omnipolar Switch Sensor



Direct Omnipolar Switch

3-Axis Programmable Hall Effect Latch/Switch Datasheet



#### 11.5. Indexing magnet reference positions

#### 11.5.1. TSOT-5L package



XY configuration

3-Axis Programmable Hall Effect Latch/Switch Datasheet



#### 11.5.2. VA package



3-Axis Programmable Hall Effect Latch/Switch Datasheet



# **12. Typical Application Schematic**



3-Axis Programmable Hall Effect Latch/Switch Datasheet



#### **13. Package Information**

#### 13.1. TSOT-5L (SE Package)

#### 13.1.1. TSOT-5L – Package dimensions





S≻∑BOL	MINIMUM	MAXIMUM
А		1.00
A1	0.025	0.10
A2	0.85	0.90
D	2.80	3.00
E	2.60	3.00
E1	1.50	1.70
L	0.30	0.50
b	0.30	0.45
с	0.10	0.20
е	0.95	BSC
e1	1.90	BSC
α	0°	8°

NOTE :

1. ALL DIMENSIONS IN MILLIMETERS (mm) UNLESS OTHERWISE STATED.

2. DIMENSION D DOES NOT INCLUDE MOLD FLASH OR PROTRUSIONS OF MAX 0.15 mm PER SIDE.

3. DIMENSION E DOES NOT INCLUDE MOLD FLASH OR PROTRUSIONS OF MAX 0.25 mm PER SIDE.

4. DIMENSION & DOES NOT INCLUDE DAMBAR PROTRUSION OF MAX 0.07 mm.

5. DIMENSION L IS THE LENGTH OF THE TERMINAL FOR SOLDERING TO A SUBTRATE.

6. FORMED LEAD SHALL BE PLANAR WITH RESPECT TO ONE ANOTHER WITH 0.076 mm SEATING PLANE.

#### 13.1.2. TSOT-5L – Sensitive spot



3-Axis Programmable Hall Effect Latch/Switch Datasheet



# 13.1.3. TSOT-5L – Package marking



3-Axis Programmable Hall Effect Latch/Switch Datasheet



#### 13.2. VA package

#### 13.2.1. VA – Package dimensions



SYMBOLS	DIMENSIONS IN MILLIMETERS		
	MIN	NOM	MAX
А	3.30	3.38	3.46
A1	3.63	3.71	3.79
D	5.08	5.16	5.24
D1	5.33	5.38	5.43
E	1.10		1.20
J	4.10	4.30	4.50
J1	1.00 REF		
К	0.00		0.15
K1	0.25	0.30	0.35
L	17.5	18.0	18.5
L1	0.48	0.53	0.58
S	0.24		0.29
Т	0.61		0.66
b1	0.35		0.48
b2	0.40		0.60
с	0.18		0.34
е	3.76		3.86
e1	1.22	1.27	1.32
Θ1	5° REF		
Θ2	45° REF		

- Note: 1. DIMENSIONS "A" AND "D" DO NOT INCLUDE MOLD FLASH, PROTRUSIONS AND GATE BURRS.
- 2. DIMENSIONS "A1" DOES NOT INCLUDE GATE BURRS BUT INCLUDES MOLD FLASH AT BOTH ENDS.
- 3. MOLD GATE BURRS SHALL NOT EXCEED 0.15 mm MEASURED FROM EDGE OF MOLD FLASH (FLANGE).
- 4. DIMENSION "D1" INCLUDES MOLD FLASH AT BOTH ENDS.
- 5. LEAD PLATING; MATTE TIN PLATING THICKNESS 7.62 15.42 um.
- ITE LEADS MAY BE SLIGHTLY DEFORMED DURING TRANSPORTATION IF PACKE IN BULK (BAG), AFFECTING e1 DIMENSION. IT IS RECOMMENDED TO ORDER RADIAL TAPE (REEL OR AMMOPACK) IF SUCH DEFORMATION IS CRITICAL FOR THE LEAD FORMING PROCESS, EVEN IF MANUAL LOADING INTO THE TOOL IS FORESEEN. 6. THE LEADS MAY BE SLIGHTLY DEFORMED DURING TRANSPORTATION IF PACKED

#### 13.2.2. VA – Sensitive spot





3-Axis Programmable Hall Effect Latch/Switch Datasheet



#### 13.2.3. VA – Package marking



3-Axis Programmable Hall Effect Latch/Switch Datasheet



### **14. Standard Information**

#### 14.1. Storage and handling of plastic encapsulated ICs

Plastic encapsulated ICs shall be stored and handled according to their MSL categorization level (specified in the packing label) as per J-STD-033.

Electronic semiconductor products are sensitive to Electro Static Discharge (ESD). The component assembly shall be handled in EPA (Electrostatic Protected Area) as per ANSI S20.20.

For more information refer to Melexis *Guidelines for storage and handling of plastic encapsulated ICs* <sup>(1)</sup>

#### 14.2. Assembly of encapsulated ICs

For Surface Mounted Devices (SMD, as defined according to JEDEC norms), the only applicable soldering method is reflow.

For Through Hole Devices (THD), the applicable soldering methods are reflow, wave, selective wave and robot point-to-point. THD lead pre-forming (cutting and/or bending) is applicable under strict compliance with Melexis *Guidelines for lead forming of SIP Hall Sensors*<sup>(18)</sup>.

Melexis products soldering on PCB should be conducted according to the requirements of IPC/JEDEC and J-STD-001. Solder quality acceptance should follow the requirements of IPC-A-610.

For PCB-less assembly refer to the relevant application notes <sup>(18)</sup> or contact Melexis.

Electrical resistance welding or laser welding can be applied to Melexis products in THD and specific PCB-less packages following the <u>Guidelines for welding of PCB-less devices</u> <sup>(18)</sup>.

Environmental protection of customer assembly with Melexis products for harsh media application, is applicable by means of coating, potting or overmolding considering restrictions listed in the relevant application notes <sup>(18)</sup>.

For other specific process, contact Melexis via www.melexis.com/technical-inquiry

#### 14.3. Environment and sustainability

Melexis is contributing to global environmental conservation by promoting non-hazardous solutions. For more information on our environmental policy and declarations (RoHS, REACH...) visit www.melexis.com/environmental-forms-and-declarations

### **15. ESD Precautions**

Electronic semiconductor products are sensitive to Electro Static Discharge (ESD). Always observe Electro Static Discharge control procedures whenever handling semiconductor products.

<sup>&</sup>lt;sup>1</sup> www.melexis.com/ic-handling-and-assembly

3-Axis Programmable Hall Effect Latch/Switch Datasheet



#### 16. Contact

For the latest version of this document, go to our website at www.melexis.com.

For additional information, get in touch via <u>www.melexis.com/contact</u>.

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